

Characteristics of a PV module

Manufacturer, model : **Longi Solar, LR6-72OPH-400M-157.25**

Data source : Longi 201909

STC power (manufacturer)	Pnom	400 Wp	Technology	Si-mono
Module size (W x L)	0.994 x 2.006 m ²		Rough module area	Amodule 1.99 m ²
Number of cells	6 x 64		Sensitive area (cells)	Acells N/A m ²

Specifications for the model (manufacturer or measurement data)

Reference temperature	TRef	25 °C	Reference irradiance	GRef	1000 W/m ²
Open circuit voltage	Voc	44.0 V	Short-circuit current	Isc	11.80 A
Max. power point voltage	Vmpp	36.2 V	Max. power point current	Impp	11.05 A
=> maximum power	Pmpp	400.0 W	Isc temperature coefficient	mulsc	6.6 mA/°C

One-diode model parameters

Shunt resistance	Rshunt	2100 ohm	Diode saturation current	IoRef	0.223 nA
Serie resistance	Rserie	0.26 ohm	Voc temp. coefficient	MuVoc	-134 mV/°C
			Diode quality factor	Gamma	1.08
Specified Pmax temper. coeff.	muPMaxR	-0.37 %/°C	Diode factor temper. coeff.	muGamma	-0.001 1/°C

Reverse Bias Parameters, for use in behaviour of PV arrays under partial shadings or mismatch

Reverse characteristics (dark)	BRev	3.20 mA/V ²	(quadratic factor (per cell))	
Number of by-pass diodes per module		2	Direct voltage of by-pass diodes	-0.5 V

Model results for standard conditions (STC: T=25° C, G=1000 W/m², AM=1.5)

Max. power point voltage	Vmpp	35.8 V	Max. power point current	Impp	11.19 A
Maximum power	Pmpp	400.5 Wc	Power temper. coefficient	muPmpp	-0.36 %/°C
Efficiency(/ Module area)	Eff_mod	20.1 %	Fill factor	FF	0.771
Efficiency(/ Cells area)	Eff_cells	N/A %			

